1.5GHz to 2.5GHz Direct Conversion Quadrature Demodulator

FEATURES

- Frequency Range: 1.5GHz to 2.5GHz
- High IIP3: 20dBm at 1.9GHz
- High IIP2: 51dBm at 1.9GHz
- Noise Figure: 16.8dB at 1.9GHz
- Conversion Gain: –0.7dB at 1.9GHz
- I/Q Gain Mismatch: 0.3dB
- I/Q Phase Mismatch: 1°
- Shutdown Mode
- 16-Lead QFN 4mm × 4mm Package with Exposed Pad

APPLICATIONS

- Cellular/PCS/UMTS Infrastructure
- High Linearity Direct Conversion I/Q Receiver
- High Linearity I/Q Demodulator
- RF Power Amplifier Linearization

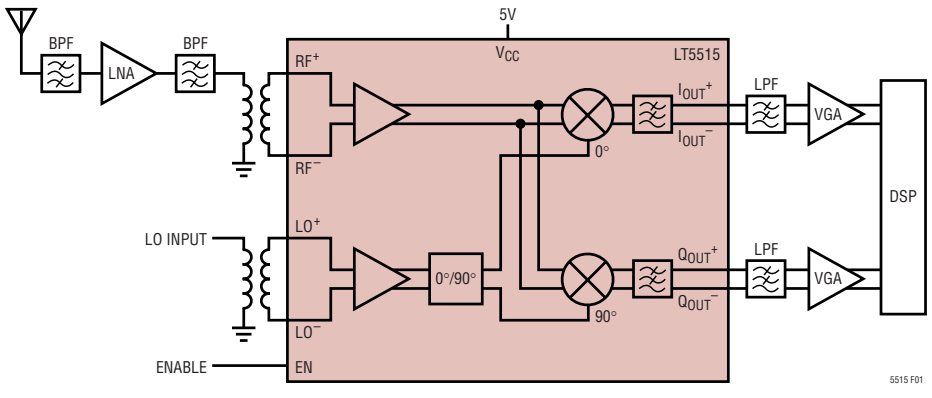
DESCRIPTION

The LT®5515 is a 1.5GHz to 2.5GHz direct conversion quadrature demodulator optimized for high linearity receiver applications. It is suitable for communications receivers where an RF signal is directly converted into I and Q baseband signals with bandwidth up to 260MHz. The LT5515 incorporates balanced I and Q mixers, LO buffer amplifiers and a precision, high frequency quadrature generator.

In an RF receiver, the high linearity of the LT5515 provides excellent spur-free dynamic range, even with fixed gain front end amplification. This direct conversion receiver can eliminate the need for intermediate frequency (IF) signal processing, as well as the corresponding requirements for image filtering and IF filtering. Channel filtering can be performed directly at the outputs of the I and Q channels. These outputs can interface directly to channel-select filters (LPFs) or to a baseband amplifier.

LT, LTC and LTM are registered trademarks of Linear Technology Corporation.
All other trademarks are the property of their respective owners.

TYPICAL APPLICATION



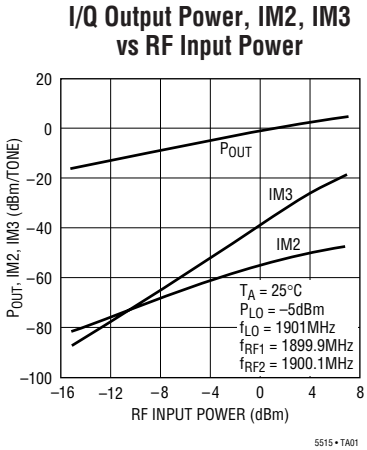


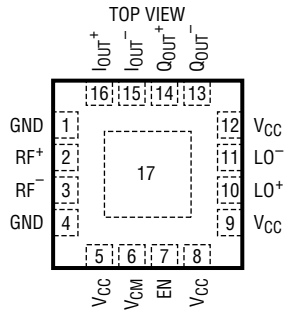
Figure 1. High Signal-Level I/Q Demodulator for Wireless Infrastructure

ABSOLUTE MAXIMUM RATINGS

(Note 1)

Power Supply Voltage 5.5V
Enable Voltage ..... 0, V_{CC}
LO^+ to LO^- Differential Voltage ..... ±2V
(+10dBm Equivalent)
RF^+ to RF^- Differential Voltage ..... ±2V
(+10dBm Equivalent)
Operating Ambient Temperature ..... –40°C to 85°C
Storage Temperature Range ..... –65°C to 125°C
Maximum Junction Temperature ..... 125°C

PACKAGE/ORDER INFORMATION



UF PACKAGE
16-LEAD (4mm × 4mm) PLASTIC QFN
EXPOSED PAD (PIN 17) IS GND,
MUST BE SOLDERED TO PCB
T_{JMAX} = 125°C, θ_{JA} = 38°C/W

ORDER PART NUMBER
LT5515EUF
UF PART MARKING
5515

Order Options Tape and Reel: Add #TR
Lead Free: Add #PBF Lead Free Tape and Reel: Add #TRPBF
Lead Free Part Marking: http://www.linear.com/leadfree/

Consult LTC Marketing for parts specified with wider operating temperature ranges.

AC ELECTRICAL CHARACTERISTICS

T_A = 25°C. V_{CC} = 5V, f_{RF1} = 1899.9MHz, f_{RF2} = 1900.1MHz, f_{LO} = 1901MHz, P_{LO} = –5dBm unless otherwise noted. (Notes 2, 3) (Test circuit shown in Figure 2)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Frequency Range			1.5 to 2.5		GHz
LO Power			–10 to 0		dBm
Conversion Gain	Voltage Gain, Load Impedance = 1k	–3	–0.7		dB
Noise Figure			16.8		dB
Input 3rd Order Intercept	2-Tone, –10dBm/Tone, Δf = 200kHz		20		dBm
Input 2nd Order Intercept	2-Tone, –10dBm/Tone, Δf = 200kHz		51		dBm
Input 1dB Compression			9		dBm
Baseband Bandwidth			260		MHz
I/Q Gain Mismatch	(Note 4)		0.3	0.7	dB
I/Q Phase Mismatch	(Note 4)		1		deg
Output Impedance	Differential		120		Ω
LO to RF Leakage			–46		dBm
RF to LO Isolation			46		dB

DC ELECTRICAL CHARACTERISTICS

T_A = 25°C. V_{CC} = 5V unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage		4		5.25	V
Supply Current		95	125	160	mA
Shutdown Current	EN = Low			20	µA
Turn-On Time			120		ns
Turn-Off Time			650		ns
EN = High (On)		1.6			V
EN = Low (Off)				1.3	V
EN Input Current	V_{ENABLE} = 5V		2		µA
Output DC Offset Voltage ($\lvert I_{OUT}^+ - I_{OUT}^- \rvert$, $\lvert Q_{OUT}^+ - Q_{OUT}^- \rvert$)	f_{LO} = 1901MHz, P_{LO} = –5dBm		4	25	mV
Output DC Offset Variation vs Temperature	–40°C to 85°C		30		µV/°C

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: Tests are performed as shown in the configuration of Figure 2 with R1 = 8.2Ω, unless otherwise noted.

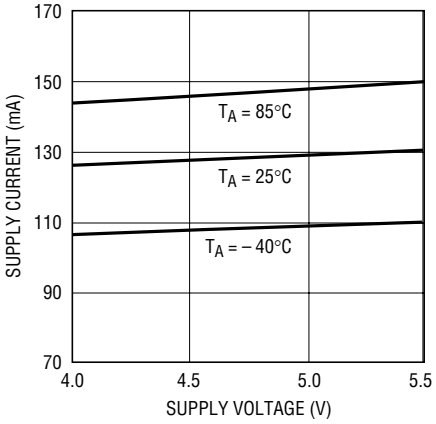
Note 3: Specifications over the –40°C to 85°C temperature range are assured by design, characterization and correlation with statistical process control.

Note 4: Measured at P_{RF} = –5dBm and output frequency = 1MHz.

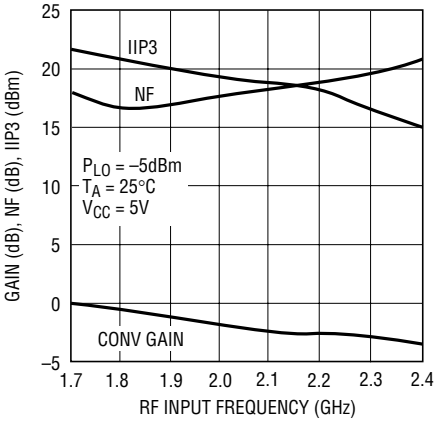
TYPICAL PERFORMANCE CHARACTERISTICS

(Test circuit optimized for 1.9GHz operation as shown in Figure 2)

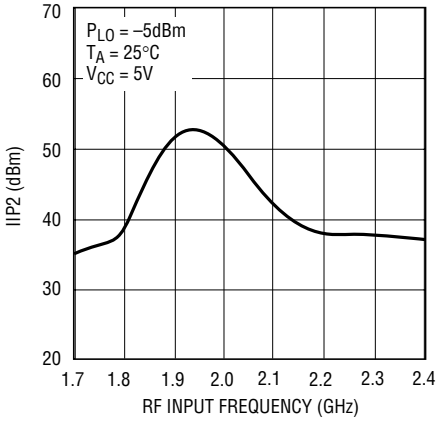
Supply Current vs Supply Voltage



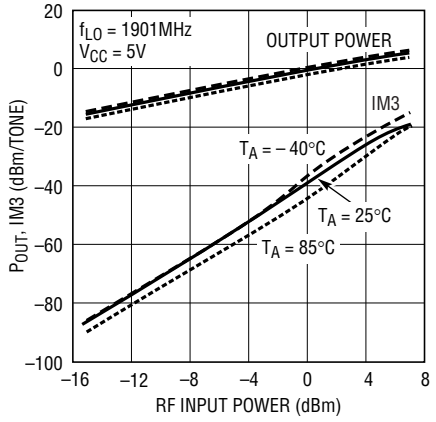
Conv Gain, NF, IIP3 vs RF Input Frequency



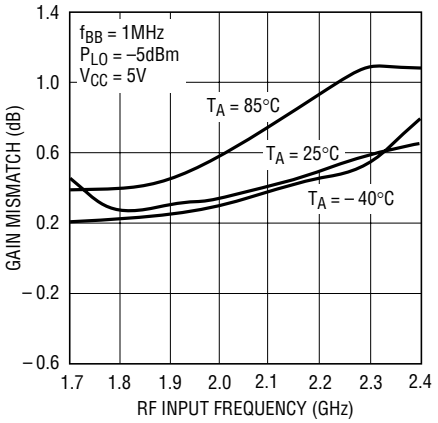
IIP2 vs RF Input Frequency



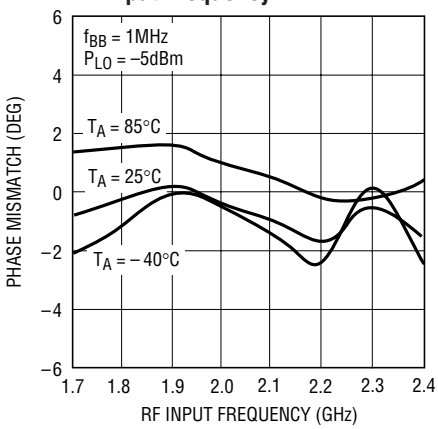
I/Q Output Power, IM3 vs RF Input Power



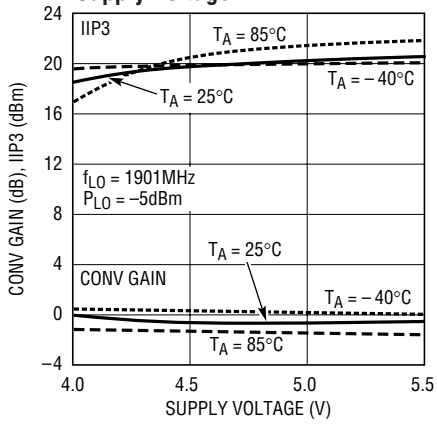
I/Q Gain Mismatch vs RF Input Frequency



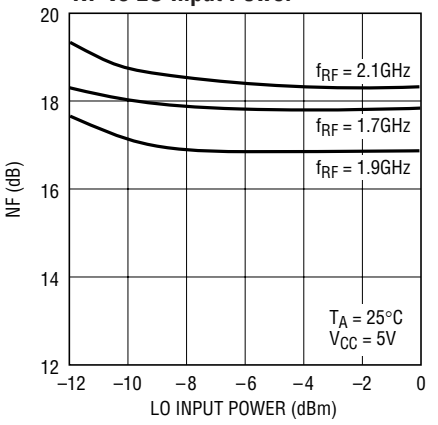
I/Q Phase Mismatch vs RF Input Frequency



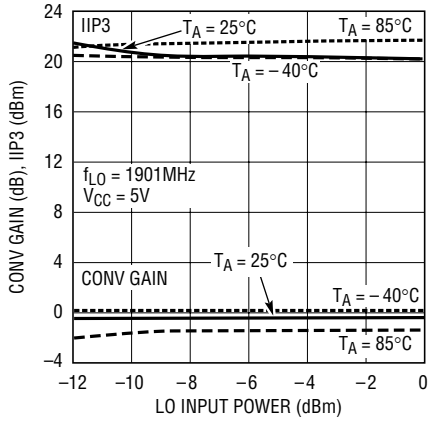
Conv Gain, IIP3 vs Supply Voltage



NF vs LO Input Power



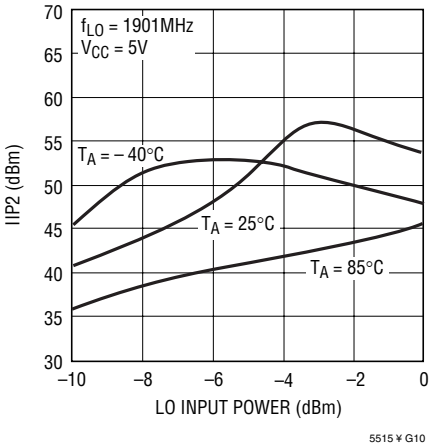
Conv Gain, IIP3 vs LO Input Power



TYPICAL PERFORMANCE CHARACTERISTICS

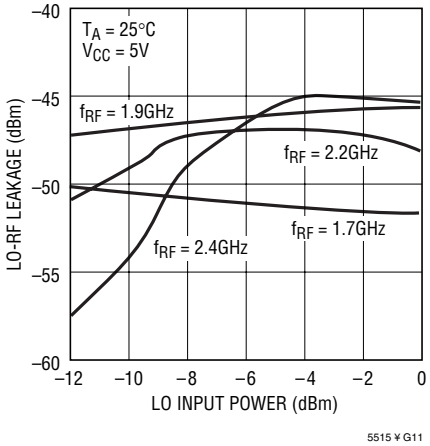
(Test circuit optimized for 1.9GHz operation as shown in Figure 2)

IIP2 vs LO Input Power



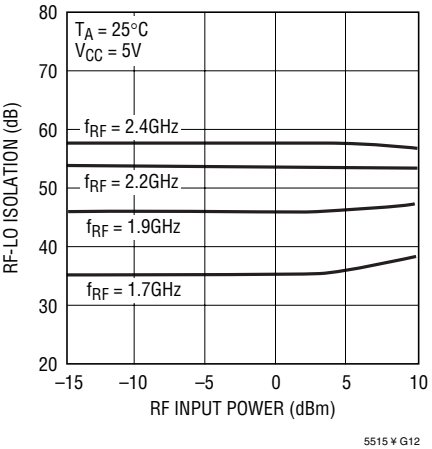
5515 ¥ G10

LO-RF Leakage vs LO Input Power



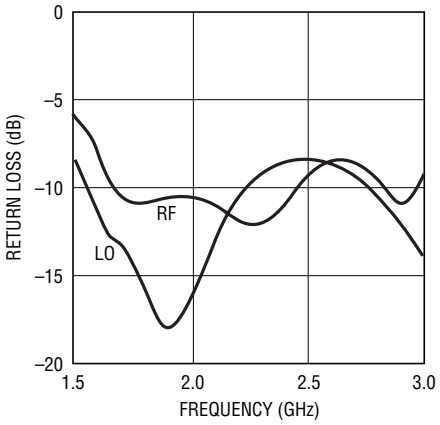
5515 ¥ G11

RF-LO Isolation vs RF Input Power



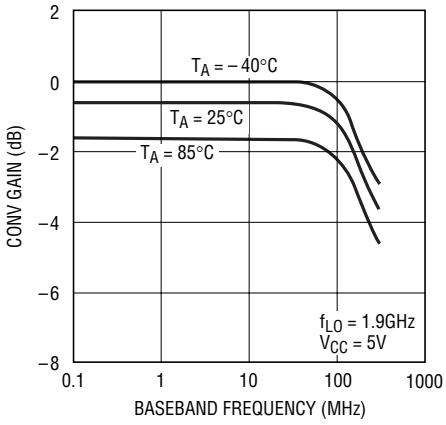
5515 ¥ G12

RF, LO Port Return Loss vs Frequency



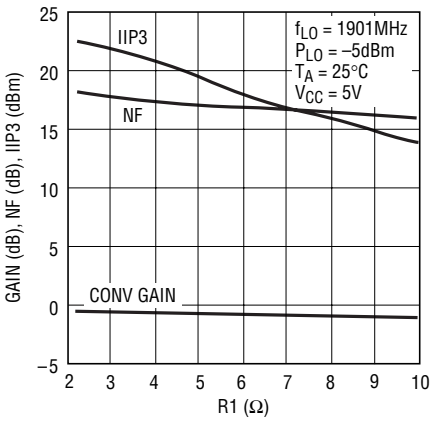
5515 ¥ G13

Conv Gain vs Baseband Frequency



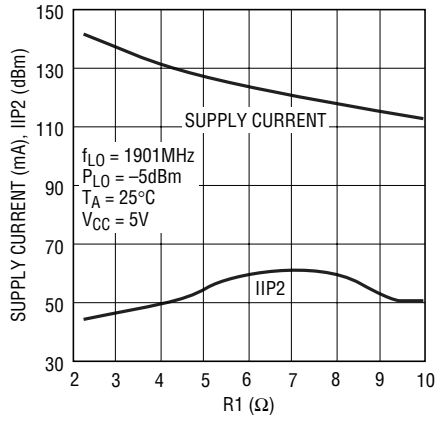
5515 ¥ G14

Conv Gain, NF, IIP3 vs R1



5515 ¥ G15

Supply Current, IIP2 vs R1



5515 ¥ G16

PIN FUNCTIONS

GND (Pins 1, 4): Ground Pin.

RF+, RF– (Pins 2, 3): Differential RF Input Pins. These pins are internally biased to 1.54V. They must be driven with a differential signal. An external matching network is required for impedance transformation.

V_{CC} (Pins 5, 8, 9, 12): Power Supply Pins. These pins should be decoupled using 1000pF and 0.1µF capacitors.

V_{CM} (Pin 6): Common Mode and DC Return for the I-Mixer and Q-Mixer. An external resistor must be connected between this pin and ground to set the DC bias current of the I/Q demodulator.

EN (Pin 7): Enable Pin. When the input voltage is higher than 1.6V, the circuit is completely turned on. When the input voltage is less than 1.3V, the circuit is turned off.

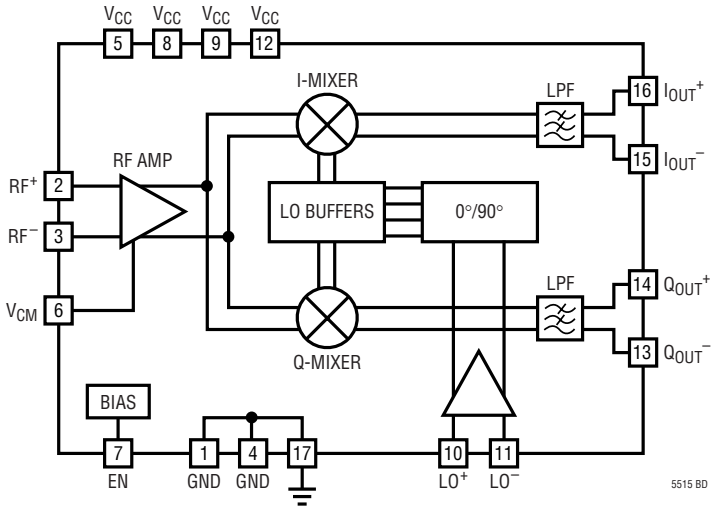
LO+, LO– (Pins 10, 11): Differential Local Oscillator Input Pins. These pins are internally biased to 2.44V. They can be driven single-ended by connecting one to an AC ground through a 1000pF capacitor. However, differential input drive is recommended to minimize LO feedthrough to the RF input pins.

Q_{OUT}^-, Q_{OUT}^+ (Pins 13, 14): Differential Baseband Output Pins of the Q-Channel. The internal DC bias voltage is V_{CC} –0.85V for each pin.

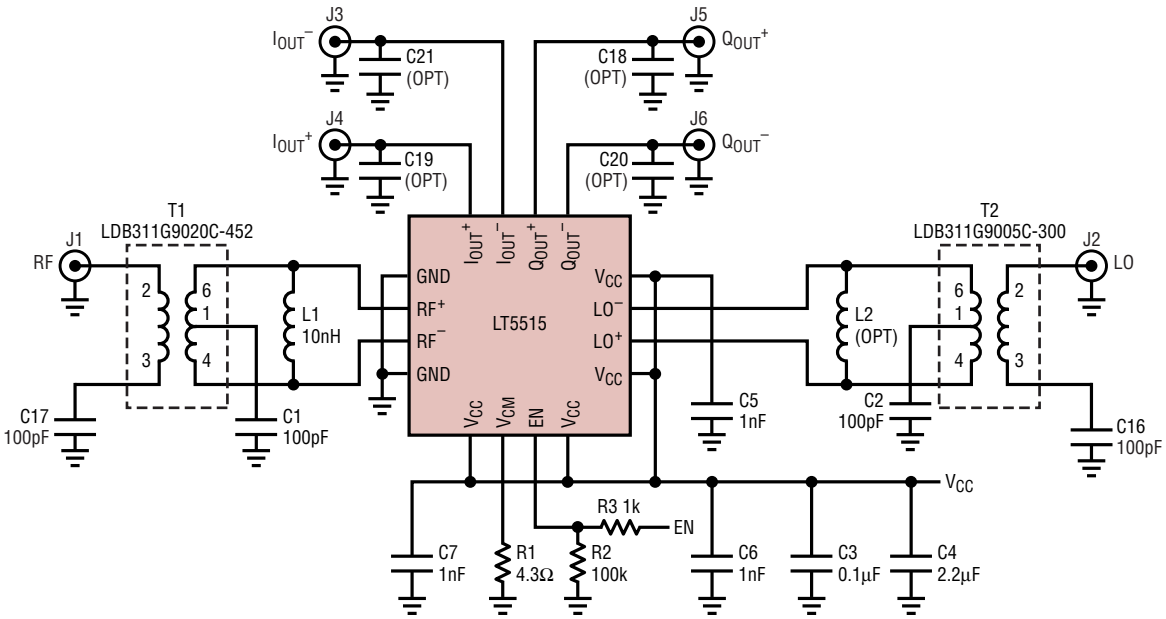
I_{OUT}^-, I_{OUT}^+ (Pins 15, 16): Differential Baseband Output Pins of the I-Channel. The internal DC bias voltage is V_{CC} –0.85V for each pin.

GROUND (Pin 17, Backside Contact): Ground Return for the Entire IC. This pin must be soldered to the printed circuit board ground plane.

BLOCK DIAGRAM



TEST CIRCUITS



REFERENCE DESIGNATION	VALUE	SIZE	PART NUMBER
C1, C2, C16, C17	100pF	0402	AVX 04025C101JAT
C5, C6, C7	1nF	0402	AVX 04025C102JAT
C3	0.1µF	0402	AVX 0402ZD104KAT
C4	2.2µF	3216	AVX TPSA225M010R1800
L1	10nH	0402	Murata LQP15M
R1	4.3Ω	0402	
R2	100k	0402	
R3	1k	0402	
T1	1:4		Murata LDB311G9020C-452
T2	1:1		Murata LDB311G9005C-300

5515 F02

Figure 2. Evaluation Circuit Schematic for 1900MHz PCS/UMTS Application

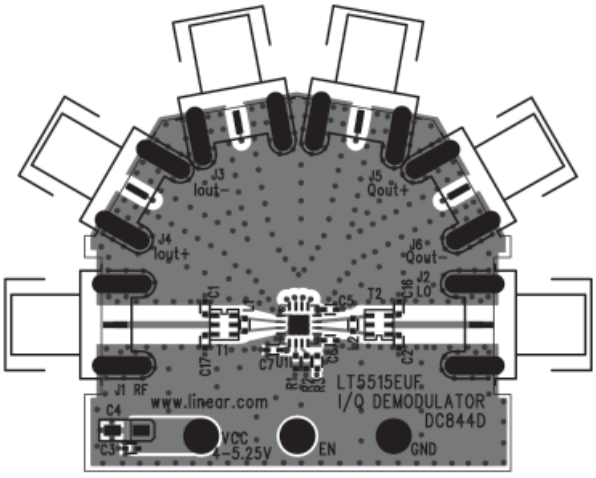


Figure 3. Topside of Evaluation Board

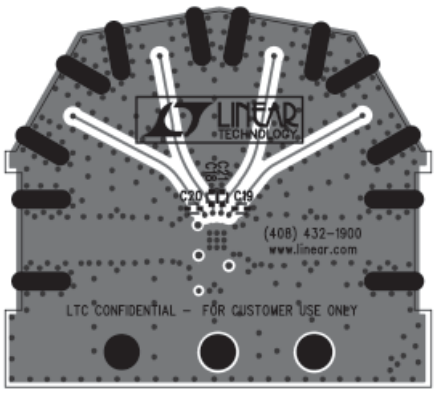


Figure 4. Bottom Side of Evaluation Board

APPLICATIONS INFORMATION

The LT5515 is a direct I/Q demodulator targeting high linearity receiver applications, including wireless infrastructure. It consists of an RF amplifier, I/Q mixers, a quadrature LO carrier generator and bias circuitry.

The RF signal is applied to the inputs of the RF amplifier and is then demodulated into I/Q baseband signals using quadrature LO signals. The quadrature LO signals are internally generated by precision 90° phase shifters. The demodulated I/Q signals are lowpass filtered internally with a –3dB bandwidth of 260MHz. The differential outputs of the I-channel and Q-channel are well matched in amplitude; their phases are 90° apart.

RF Input Port

Differential drive is highly recommended for the RF inputs to minimize the LO feedthrough to the RF port and to maximize gain. (See Figure 2.) A 1:4 transformer is used on the demonstration board for wider bandwidth matching. To assure good NF and maximize the demodulator gain, a low loss transformer is employed. Shunt inductor L1, with high resonance frequency, is required for proper impedance matching. Single-ended to differential conversion can also be implemented using narrow band, discrete L-C circuits to produce the required balanced waveforms at the RF^+ and RF^- inputs.The differential impedance of the RF inputs is listed in Table 1.

Table 1. RF Input Differential Impedance

FREQUENCY (GHz)	DIFFERENTIAL INPUT IMPEDANCE (Ω)	DIFFERENTIAL S11	
		MAG	ANGLE(°)
1.5	115.7-j132.7	0.698	–24.9
1.6	111.7-j128.1	0.689	–25.9
1.7	108.1-j123.7	0.681	–26.8
1.8	104.8-j120.2	0.674	–27.7
1.9	101.7-j116.9	0.667	–28.5
2.0	98.8-j113.8	0.661	–29.4
2.1	96.0-j111.1	0.655	–30.2
2.2	93.3-j108.7	0.650	–31.1
2.3	90.7-j106.2	0.645	–32.0
2.4	88.3-j104.2	0.641	–32.8
2.5	85.9-j102.2	0.637	–33.7

The RF^+ and RF^- inputs (Pins 2, 3) are internally biased at 1.54V. These two pins should be DC blocked when connected to ground or other matching components. The RF input equivalent circuit is shown in Figure 5.

A 4.3Ω resistor (R1) is connected to Pin 6 (V_{CM}) to set the optimum DC current for I/Q mixer linearity. The trade-off of the NF and IIP3 as a function of R1 is shown in the "Typical Performance Characteristics". When a smaller R1 is used for better linearity, the total supply current will increase. A 5V ±5% power supply is recommended to assure high linearity performance.

LO Input Port

The LO inputs (Pins 10,11) should be driven differentially to minimize LO feedthrough to the RF port. This can be accomplished by means of a single-ended to differential conversion as shown in Figure 2. L4, the 12nH shunt inductor, serves to tune out the capacitive component of the LO differential input. The resonance frequency of the inductor should be greater than the operating frequency. A 1:2 transformer is used on the demo board to match the LO port to a 50Ω source. Figure 6 shows the LO input equivalent circuit and the associated matching network.

Single-ended to differential conversion at the LO inputs can also be implemented using a discrete L-C circuit to produce a balanced waveform without a transformer.

An alternative solution is a simple single-ended termination. However, the LO feedthrough to RF may be degraded. Either LO^+ or LO^- input can be terminated to a 50Ω source with a matching circuit, while the other input is connected to ground through a 100pF bypass capacitor.

APPLICATIONS INFORMATION

Table 2 shows the differential input impedance of the LO input port.

Table 2. LO Input Differential Impedance

FREQUENCY	DIFFERENTIAL INPUT	DIFFERENTIAL S11	
(GHz)	IMPEDANCE (Ω)	MAG	ANGLE (°)
1.5	69.3-j59.4	0.469	–45.8
1.6	64.3-j56.4	0.457	–49.8
1.7	60.0-j52.7	0.440	–53.9
1.8	56.4-j48.9	0.421	–58.0
1.9	53.7-j44.9	0.399	–62.2
2.0	51.4-j41.2	0.377	–66.1
2.1	49.8-j37.5	0.352	–69.9
2.2	48.6-j34.2	0.328	–73.3
2.3	47.8-j31.0	0.303	–76.5
2.4	47.3-j28.2	0.279	–79.5
2.5	46.9-j25.6	0.257	–82.3

I-Channel and Q-Channel Outputs

Each of the I-channel and Q-channel outputs is internally connected to V_{CC} though a 60Ω resistor. The output DC bias voltage is V_{CC} – 0.85V. The outputs can be DC coupled or AC coupled to the external loads. The differential output impedance of the demodulator is 120Ω in parallel with a 5pF internal capacitor, forming a lowpass filter with a –3dB corner frequency at 260MHz. R_{LOAD} (the single-ended load resistance) should be larger than 600Ω to assure full gain. The gain is reduced by 20 • log(1 + 120Ω/R_{LOAD}) in dB when the differential output is terminated by R_{LOAD}. For instance, the gain is reduced by 6.85dB when each output pin is connected to a 50Ω load (100Ω differential load). The output should be taken differentially (or by using differential-to-single-ended conversion) for best RF performance, including NF and IM2.

The phase relationship between the I-channel output signal and Q-channel output signal is fixed. When the LO input frequency is larger (or smaller) than the RF input frequency, the Q-channel outputs (Q_{OUT}^+, Q_{OUT}^-) lead (or lag) I-channel outputs (I_{OUT}^+, I_{OUT}^-) by 90°.

When AC output coupling is used, the resulting highpass filter's –3dB roll-off frequency is defined by the R-C constant of the blocking capacitor and R_{LOAD}, assuming R_{LOAD} > 600Ω.

Care should be taken when the demodulator's outputs are DC coupled to the external load, to make sure that the I/Q mixers are biased properly. If the current drain from each output exceeds 6mA, there can be significant degradation of the linearity performance. Each output can sink no more than 14mA when the outputs are connected to an external load with a DC voltage higher than V_{CC} – 0.85V. The I/Q output equivalent circuit is shown in Figure 7.

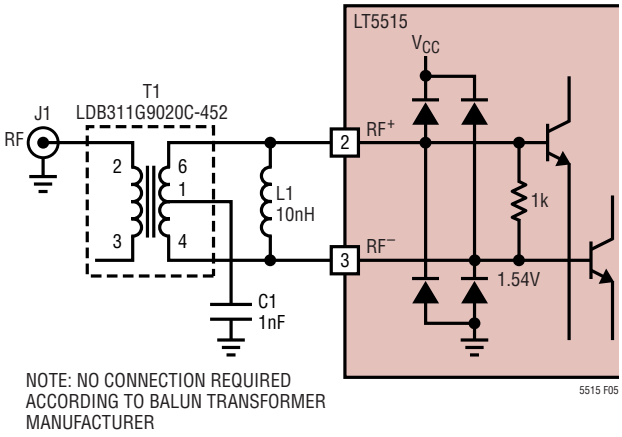


Figure 5. RF Input Equivalent Circuit with External Matching at 1.9GHz

APPLICATIONS INFORMATION

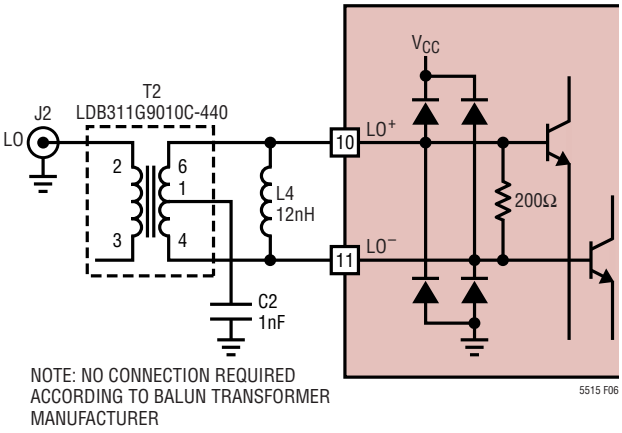


Figure 6. LO Input Equivalent Circuit with External Matching at 1.9GHz

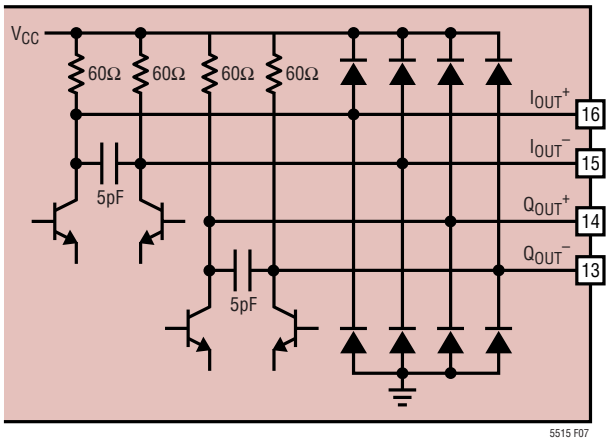
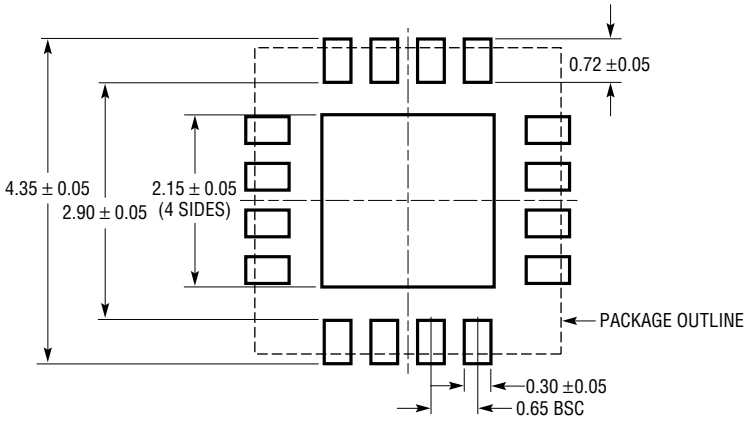


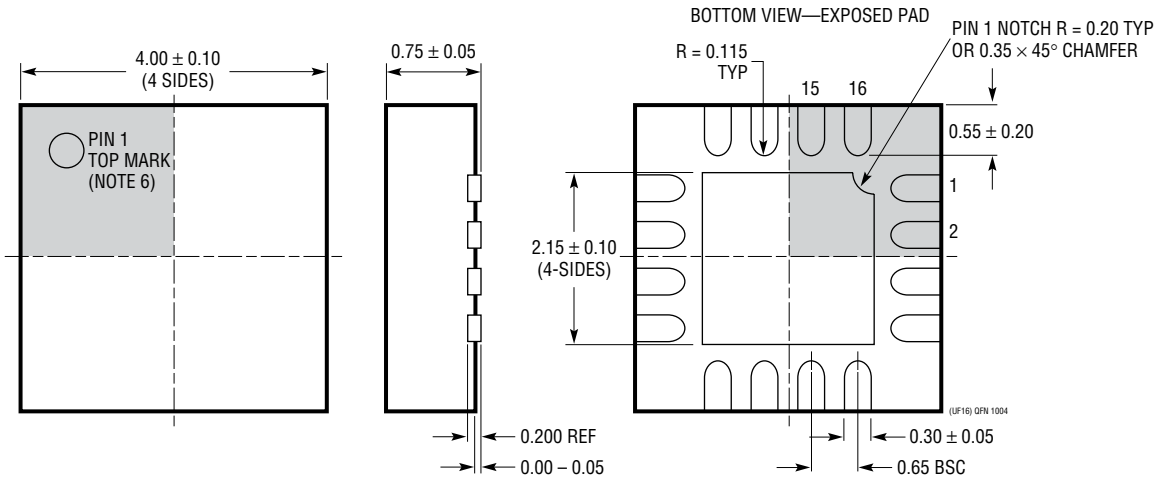
Figure 7. I/Q Output Equivalent Circuit

PACKAGE DESCRIPTION

UF Package
16-Lead Plastic QFN (4mm × 4mm)
(Reference LTC DWG # 05-08-1692)



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS



NOTE:
1. DRAWING CONFORMS TO JEDEC PACKAGE OUTLINE MO-220 VARIATION (WGGC)
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of its circuits as described herein will not infringe on existing patent rights.

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
RF Power Controllers		
LTC1757A	RF Power Controller	Multiband GSM/DCS/GPRS Mobile Phones
LTC1758	RF Power Controller	Multiband GSM/DCS/GPRS Mobile Phones
LTC1957	RF Power Controller	Multiband GSM/DCS/GPRS Mobile Phones
LTC4400	SOT-23 RF PA Controller	Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 450kHz Loop BW
LTC4401	SOT-23 RF PA Controller	Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 250kHz Loop BW
LTC4403	RF Power Controller for EDGE/TDMA	Multiband GSM/GPRS/EDGE Mobile Phones
LT5500	RF Front End	Dual LNA gain Setting +13.5dB/–14dB at 2.5GHz, Double-Balanced Mixer, $1.8V \leq V_{SUPPLY} \leq 5.25V$
LT5502	400MHz Quadrature Demodulator with RSSI	1.8V to 5.25V Supply, 70MHz to 400MHz IF, 84dB Limiting Gain, 90dB RSSI Range
LT5503	1.2GHz to 2.7GHz Direct IQ Modulator and Up Converting Mixer	1.8V to 5.25V Supply, Four-Step RF Power Control, 120MHz Modulation Bandwidth
LT5504	800MHz to 2.7GHz RF Measuring Receiver	80dB Dynamic Range, Temperature Compensated, 2.7V to 5.5V Supply
LTC5505	300MHz to 3.5GHz RF Power Detector	>40dB Dynamic Range, Temperature Compensated, 2.7V to 6V Supply
LT5506	500MHz Quadrature IF Demodulator with VGA	1.8V to 5.25V Supply, 40MHz to 500MHz IF, –4dB to 57dB Linear Power Gain
LTC5507	100kHz to 1GHz RF Power Detector	48dB Dynamic Range, Temperature Compensated, 2.7V to 6V Supply
LTC5508	300MHz to 7GHz RF Power Detector	SC70 Package
LTC5509	300MHz to 3GHz RF Power Detector	36dB Dynamic Range, SC70 Package
LT5511	High Signal Level Up Converting Mixer	RF Output to 3GHz, 17dBm IIP3, Integrated LO Buffer
LT5512	High Signal Level Down Converting Mixer	DC-3GHz, 20dBm IIP3, Integrated LO Buffer
LT5516	800MHz to 1.5GHz Direct Conversion Quadrature Demodulator	21.5dBm IIP3, Integrated LO Quadrature Generator

Linear Technology Corporation
1630 McCarthy Blvd., Milpitas, CA 95035-7417
(408) 432-1900 • FAX: (408) 434-0507 • www.linear.com
LT 0406 REV A • PRINTED IN USA
© LINEAR TECHNOLOGY CORPORATION 2003